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# Three quadrant triacs guaranteed commutation

# BTA212 series D, E and F

### GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a plastic envelope intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

### **PINNING - TO220AB**

### QUICK REFERENCE DATA

| SYMBOL                                  | PARAMETER   | MAX.                        | MAX.                              | UNIT   |
|---|---|-----------------------------|-----------------------------------|--------|
| V <sub>DRM</sub>                        | BTA212-<br>BTA212-<br>BTA212-<br>BTA212-<br>Repetitive peak off-state<br>voltages | 600D<br>600E<br>600F<br>600 | <b>800E</b><br><b>800F</b><br>800 | V      |
| I <sub>T(RMS)</sub><br>I <sub>TSM</sub> | RMS on-state current<br>Non-repetitive peak on-state<br>current                   | 12<br>95                    | 12<br>95                          | A<br>A |

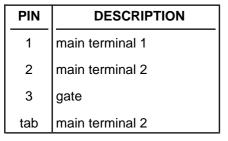
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### **PIN CONFIGURATION**

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SYMBOL

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# LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL  | PARAMETER   | CONDITIONS  | MIN.        | MAX.                            |                    | UNIT             |
|---|---|---|-------------|---------------------------------|--------------------|------------------|
| V <sub>DRM</sub>  | Repetitive peak off-state voltages  |   | -           | <b>-600</b><br>600 <sup>1</sup> | <b>-800</b><br>800 | V                |
| $I_{T(RMS)}$  | RMS on-state current  | full sine wave;   | -           | 12                              | 2                  | A                |
| I <sub>TSM</sub>  | Non-repetitive peak<br>on-state current   | $\begin{array}{l} T_{mb} \leq 99 \ ^{\circ}C \\ \text{full sine wave;} \\ T_{j} = 25 \ ^{\circ}C \ \text{prior to} \\ \text{surge} \\ t = 20 \ \text{ms} \end{array}$ | -           | 95                              |                    | A                |
| l²t<br>dI <sub>⊤</sub> /dt  | I <sup>2</sup> t for fusing<br>Repetitive rate of rise of   | t = 16.7 ms<br>t = 10 ms<br>$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$   | -           | 10<br>45<br>10                  | 5                  | Α<br>A²s<br>A/μs |
| I <sub>GM</sub><br>V <sub>GM</sub><br>P <sub>GM</sub><br>P <sub>G(AV)</sub> | on-state current after<br>triggering<br>Peak gate current<br>Peak gate voltage<br>Peak gate power<br>Average gate power | $dI_G^{\circ}/dt = 0.2 \text{ Å}/\mu s$<br>over any 20 ms<br>period   | -<br>-<br>- | 2<br>5<br>5<br>0.5              |                    | A<br>V<br>W<br>W |
| T <sub>stg</sub><br>T <sub>j</sub>  | Storage temperature<br>Operating junction<br>temperature  | F   | -40<br>-    | 150<br>129                      |                    | ູ<br>ວຸ          |

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

# BTA212 series D, E and F

### THERMAL RESISTANCES

| SYMBOL                                      | PARAMETER  | CONDITIONS                              | MIN. | TYP.         | MAX.            | UNIT              |
|---|--|---|------|--------------|-----------------|-------------------|
| R <sub>th j-mb</sub><br>R <sub>th j-a</sub> | Thermal resistance<br>junction to mounting base<br>Thermal resistance<br>junction to ambient | full cycle<br>half cycle<br>in free air |      | -<br>-<br>60 | 1.5<br>2.0<br>- | K/W<br>K/W<br>K/W |

### STATIC CHARACTERISTICS

 $T_j = 25$  °C unless otherwise stated

| SYMBOL                            | PARAMETER                                | CONDITIONS  | MIN.           | TYP.              |                | MAX.            |                | UNIT           |
|-----------------------------------|--|---|----------------|-------------------|----------------|-----------------|----------------|----------------|
|                                   |  | BTA212-   |                | D                 | D              | E               | F              |                |
| I <sub>GT</sub>                   | Gate trigger current <sup>2</sup>        | V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A<br>T2+ G+<br>T2+ G-<br>T2- G-   | -<br>-         | 1.0<br>2.2<br>3.3 | 5<br>5<br>5    | 10<br>10<br>10  | 25<br>25<br>25 | mA<br>mA<br>mA |
| I <sub>L</sub>                    | Latching current                         | $V_{D} = 12 V; I_{GT} = 0.1 A$<br>T2+ G+<br>T2+ G-<br>T2- G-  | 14 - FA        | 6<br>6<br>9       | 15<br>25<br>25 | 25<br>30<br>30  | 30<br>40<br>40 | mA<br>mA<br>mA |
| I <sub>H</sub>                    | Holding current                          | V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A  | <u>U</u> _     | 3.8               | 15             | 25              | 30             | mA             |
|                                   |  |   | D, E, F        |                   |                |                 |                |                |
| V <sub>T</sub><br>V <sub>GT</sub> | On-state voltage<br>Gate trigger voltage | $I_{T} = 17 \text{ A}$<br>$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$<br>$V_{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A};$<br>$I_{25} = 0.1 \text{ A};$ | -<br>-<br>0.25 | 1.3<br>0.7<br>0.4 |                | 1.6<br>1.5<br>- |                | V<br>V<br>V    |
| I <sub>D</sub>                    | Off-state leakage current                |   | -              | 0.1               |                | 0.5             |                | mA             |

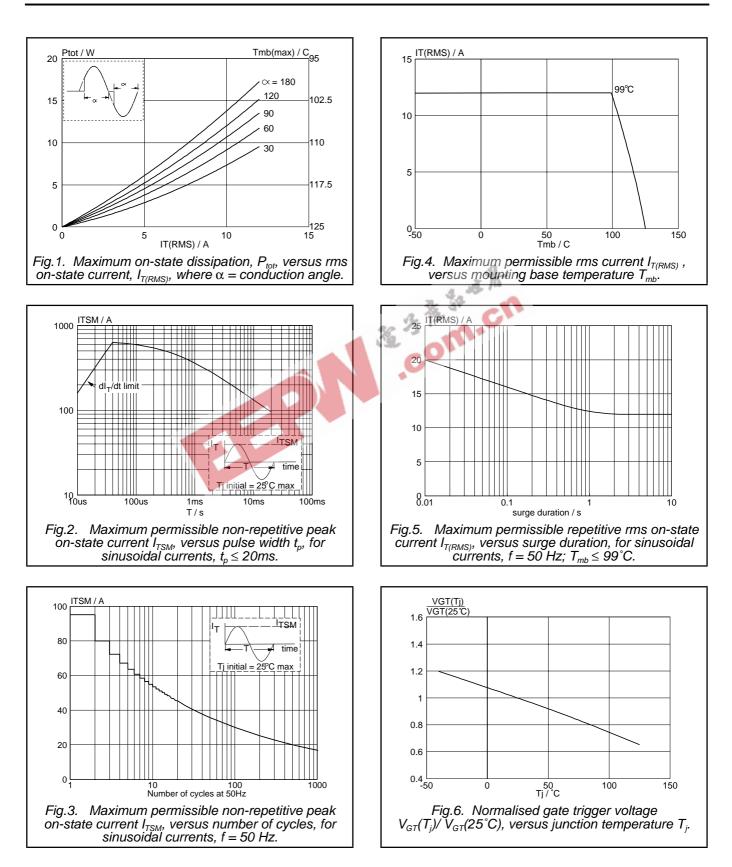
### **DYNAMIC CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise stated

| SYMBOL                | PARAMETER   | CONDITIONS   |         | MIN. |    | TYP. | MAX. | UNIT |
|-----------------------|---|--|---------|------|----|------|------|------|
|                       |   | BTA212-  | D       | E    | F  | D    |      |      |
| dV <sub>D</sub> /dt   | Critical rate of rise of off-state voltage        | $V_{DM} = 67\% V_{DRM(max)};$<br>$T_j = 110 °C; exponential waveform; gate open circuit$   | 20      | 60   | 70 | 30   | -    | V/µs |
| dl <sub>com</sub> /dt | Critical rate of change of<br>commutating current | $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 110 \text{ °C};$<br>$I_{T(RMS)} = 12 \text{ A};$<br>$dV_{com}/dt = 20V/\mu \text{s}; \text{ gate}$<br>open circuit          | 1.8     | 3.5  | 5  | 3    | -    | A/ms |
| dl <sub>com</sub> /dt | Critical rate of change of<br>commutating current | $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 110 \text{ °C};$<br>$I_{T(RMS)} = 12 \text{ A};$<br>$dV_{com}/dt = 0.1 \text{ V}/\mu\text{s}; \text{ gate}$<br>open circuit | 5       | 16   | 19 | 100  | -    | A/ms |
|                       |   |  | D, E, F |      |    |      |      |      |
| t <sub>gt</sub>       | Gate controlled turn-on time                      | $I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)};$<br>$I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A/}\mu \text{s}$  | -       | -    | -  | 2    | -    | μs   |

<sup>2</sup> Device does not trigger in the T2-, G+ quadrant.

# BTA212 series D, E and F



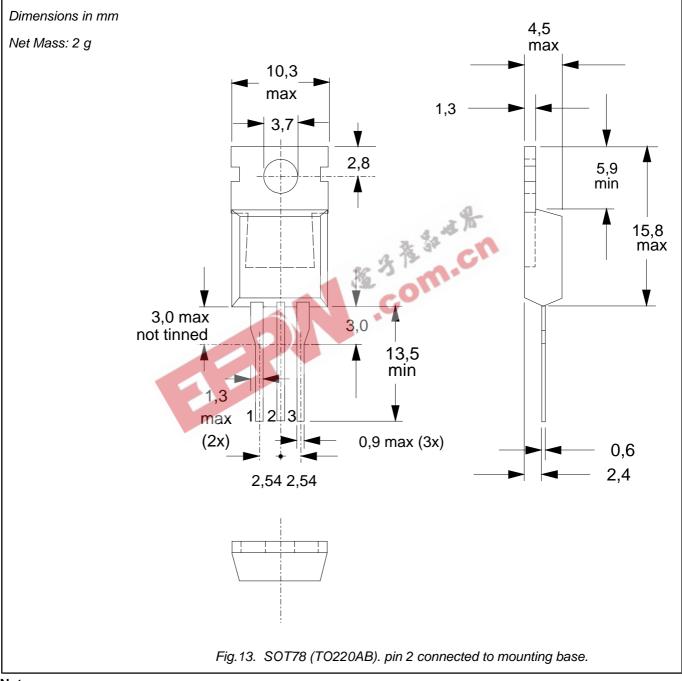
BTA212 series D, E and F

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#### IT / A IGT(Tj) IGT(25°C) 40 Tj = 125 C ----typ 3 — T2+ G+ — T2+ G-Tj = 25 C max - T2- G-2.5 30 Vo = 1.175 V Rs = 0.0316 Ohms 2 20 1.5 1 10 0.5 0∟ 0 0 1.5 VT / V 0.5 2 2.5 3 -50 0 тј/°С 100 150 Fig.7. Normalised gate trigger current $I_{GT}(T_j)/I_{GT}(25^{\circ}C)$ , versus junction temperature $T_j$ Fig.10. Typical and maximum on-state characteristic. IL(Tj) IL(25°C) 3 25 bidirectional 2 0.1 1.5 1 0.01 0.5 0.001 └ 10us 0 -50 0.1ms 10ms 0.1s 1s 10s 50 Tj /℃ 1ms 0 100 150 tp/s Fig.11. Transient thermal impedance $Z_{th j-mb}$ , versus Normalised latching current $I_L(T_i)/I_L(25^{\circ}C)$ , Fig.8. versus junction temperature $T_i$ pulse width $t_{\rm p}$ dlcom/dt (A/ms) IH(Tj) 100 3 IH(25°C - F TYPE - F TYPE DTYPE 2.5 2 10 1.5 ÷., 1 0.5 1 0 └ -50 50 Tj /℃ 20 120 40 60 100 140 100 150 80 тј/°С 0 Fig.12. Minimum Typical, critical rate of change of commutating current dl<sub>com</sub>/dt versus junction temperature, dV<sub>com</sub>/dt =20V/µs. Fig.9. Normalised holding current $I_H(T_j)/I_H(25^{\circ}C)$ , versus junction temperature $T_j$ .

# BTA212 series D, E and F

### **MECHANICAL DATA**



#### Notes

Refer to mounting instructions for SOT78 (TO220) envelopes.
 Epoxy meets UL94 V0 at 1/8".

# BTA212 series D, E and F

#### DEFINITIONS

| Data sheet status  |   |  |  |  |  |
|--|---|--|--|--|--|
| Objective specification This data sheet contains target or goal specifications for product development.  |   |  |  |  |  |
| Preliminary specification  | This data sheet contains preliminary data; supplementary data may be published later. |  |  |  |  |
| Product specification  | This data sheet contains final product specifications.                                |  |  |  |  |
| Limiting values  |   |  |  |  |  |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |   |  |  |  |  |
| Application information  |   |  |  |  |  |
| Where application information is given, it is advisory and does not form part of the specification.  |   |  |  |  |  |
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